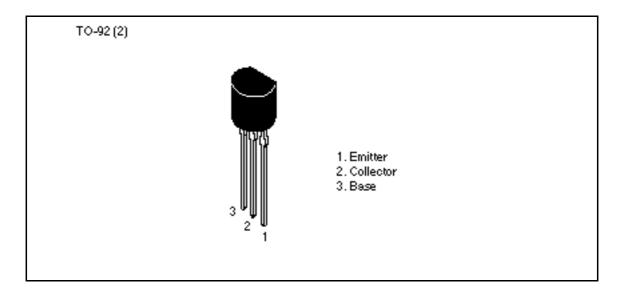
Silicon NPN Epitaxial Planar

HITACHI

Application

VHF amplifier, mixer, local oscillator

Outline



Absolute Maximum Ratings ($Ta = 25^{\circ}C$)

Item	Symbol	Ratings	Unit
Collector to base voltage	V_{CBO}	30	V
Collector to emitter voltage	V _{CEO}	20	V
Emitter to base voltage	V_{EBO}	4	V
Collector current	I _c	20	mA
Collector power dissipation	P _c	100	mW
Junction temperature	Tj	150	°C
Storage temperature	Tstg	-55 to +150	°C

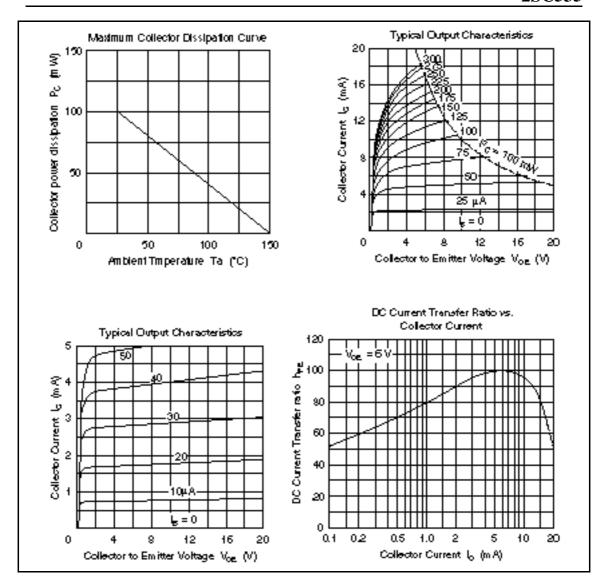


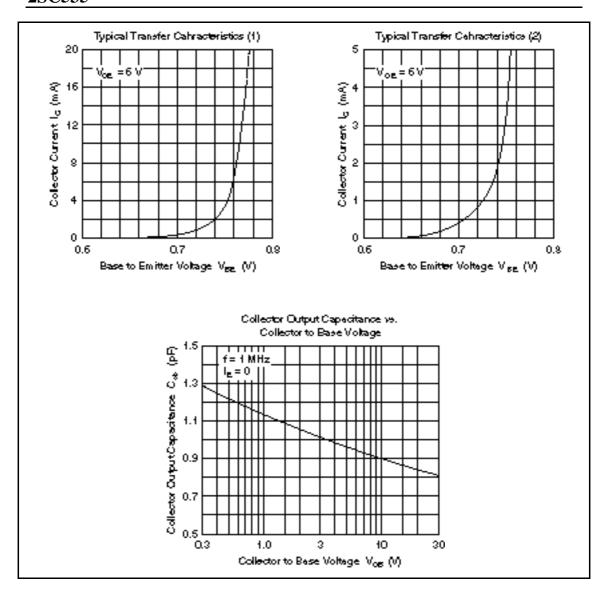
Electrical Characteristics ($Ta = 25^{\circ}C$)

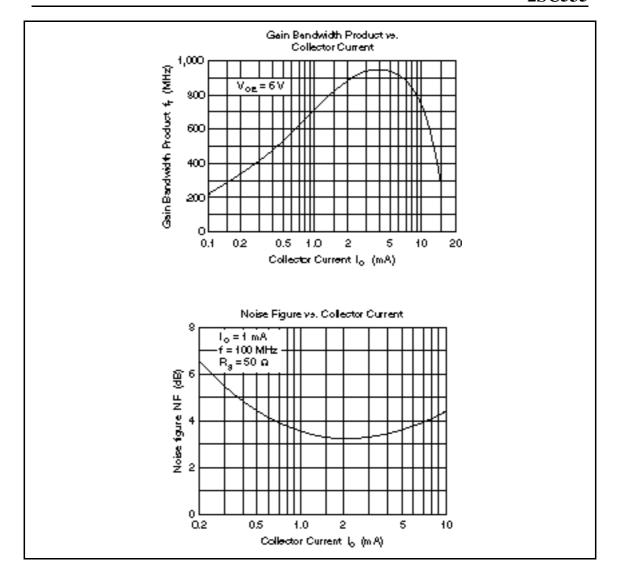
Item	Symbol	Min	Тур	Max	Unit	Test conditions
Collector to base breakdown voltage	$V_{(BR)CBO}$	30	_	_	V	$I_{c} = 10 \ \mu A, \ I_{e} = 0$
Collector to emitter breakdown voltage	$V_{(BR)CEO}$	20	_	_	V	$I_C = 1 \text{ mA}, R_{BE} =$
Emitter to base breakdown voltage	$V_{(BR)EBO}$	4	_	_	V	$I_{E} = 10 \ \mu A, \ I_{C} = 0$
Collector cutoff current	I _{CBO}	_	_	0.5	μΑ	$V_{CB} = 10 \text{ V}, I_{E} = 0$
DC current transfer ratio	h _{FE} *1	60	_	200		$V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA}$
Base to emitter voltage	V_{BE}	_	0.72	_	V	$V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	$V_{\text{CE(sat)}}$	_	0.17	_	V	$I_C = 20 \text{ mA}, I_B = 4 \text{ mA}$
Gain bandwidth product	f _T	450	940	_	MHz	$V_{CE} = 6 \text{ V}, I_{C} = 5 \text{ mA}$
Collector output capacitance	Cob	_	0.9	1.2	pF	$V_{CB} = 10 \text{ V}, I_{E} = 0, f = 1 \text{ MHz}$
Power gain	PG	17	20	_	dB	$V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA},$ f = 100 MHz
Noise figure	NF	_	3.5	5.5	dB	$V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA},$ f = 100 MHz, $R_{g} = 50$
Input admittance (typ)	yie	1.3 + j5.3			mS	$V_{CE} = 6 \text{ V}, I_{C} = 1 \text{ mA},$ f = 100 MHz
Reverse transfer admittance (typ)	yre	-0.078 - j0.41		mS	_	
Foward transfer admittance (typ)	yfe	32 – j10		mS	_	
Output admittance (typ)	yoe	0.08 + j0.82		mS	_	

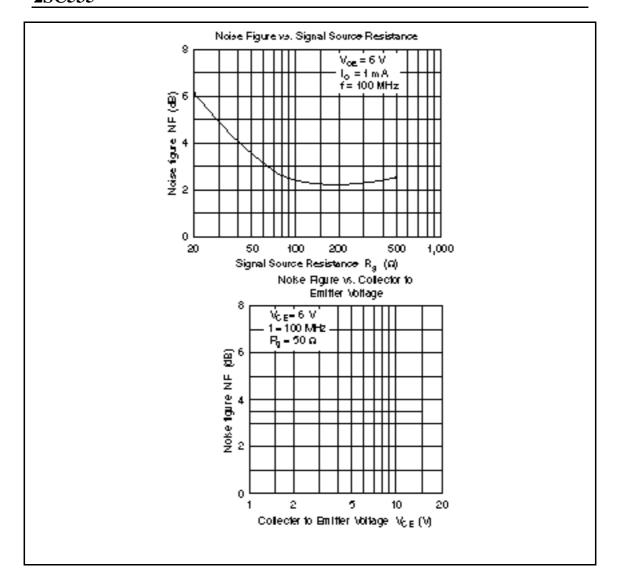
Note: 1. The 2SC535 is grouped by $h_{\rm FE}$ as follows.

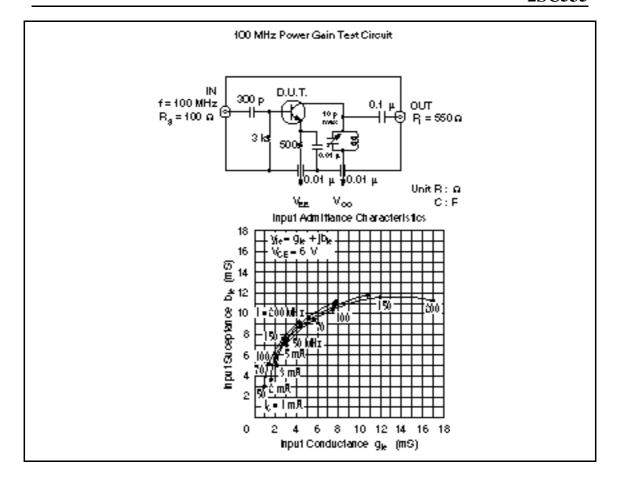
B C 60 to 120 100 to 200

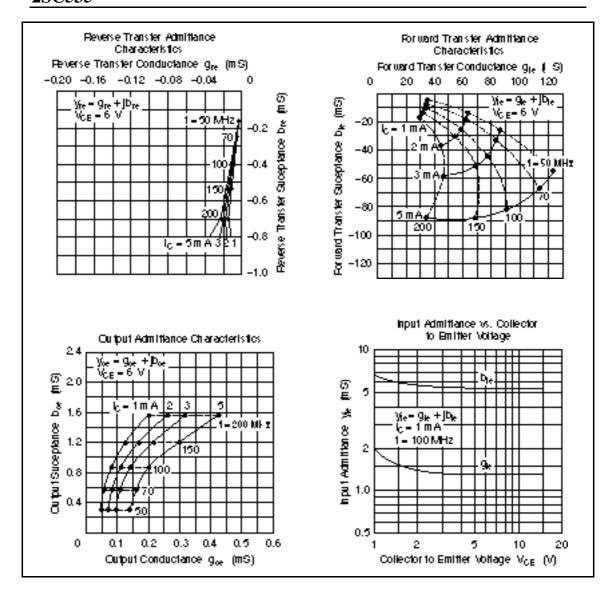


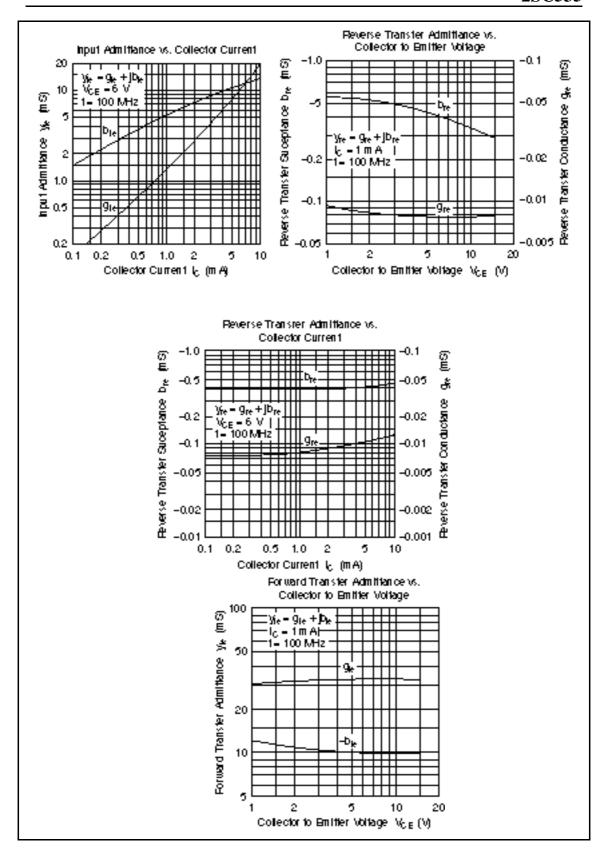


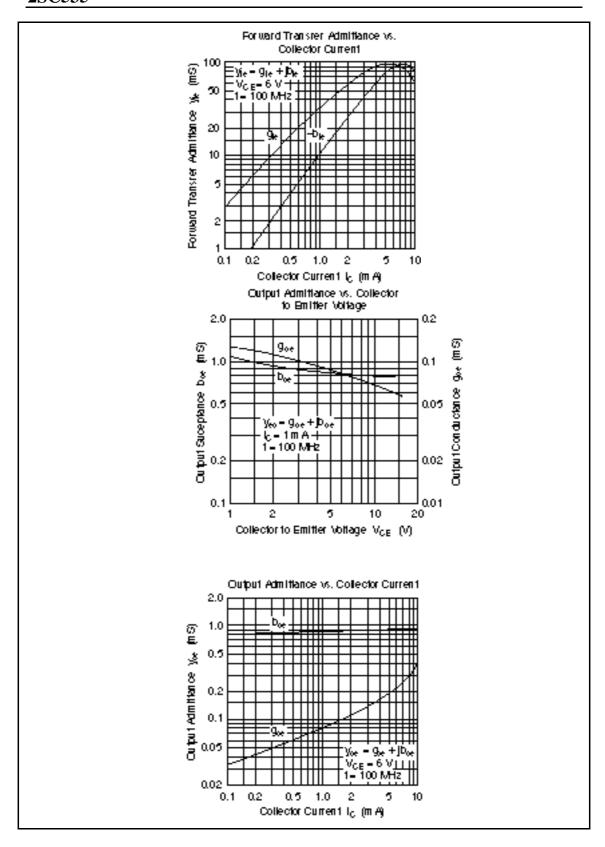












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HITACHI

Hitachi, Ltd.
Semiconductor & IC Div.
hippon Bidg., 2-6-2, Ohte-machi, Chiyoda-ku, Tokiyo 100, Japan
Tet Tokiyo (03, 3270-2111
Fex: (03, 3270-5100

For Author in formellon write to:

Hitachi Americe, Ltd. Semiconductor & IC Dw. 2000 Sierre Point Perlaway Briebene, CA. 94005-1835 U.S.A. Tet 445-589-8300 Fax: 445-583-4207 Hitechi Burope GmbH
Bedronic Componente Group
Cartinertal Burope
Darnecher Streße 3
D-85622 Feldkirchen
München
Tet 089-9 94 80-0
Fex: 089-9 29 30 00

Hitachi Burope Ltd.
Bedronic Componenta Dw.
Northern Burope Headquartera
Whitebrook Park
Lower Cook ham Road
Heidenhead
Barkshire SL68YA
Urited Kingdom
Tet 0628-858000
Fex: 0628-778322

Hitachi Asia Pta, Ltd 45 Collyer Quay \$20-00 Hitachi Tower Snappore 0404 Tet 535-2400 Fex: 535-4533

Hischi Asia (Hong Kong) Ltd. Unit 705, North Towar, World Finance Centra, Harbour City, Centon Road Taim She Taul, Kowloon Hong Kong Tet 27359218 Fax: 27306074